

Micro G Switch Bottom Contact Model AT-2150-B

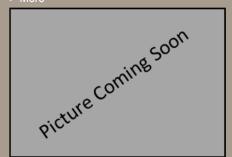
PRELIMINARY

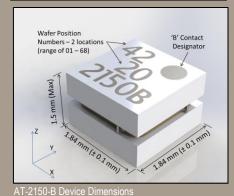
FEATURES:

- Small and Lightweight 3.4 mm²
- Extremely Fast Response Times
- High Shock Survivability 65 000+ 6
- Surface Mount Au over Ni Pads
- Tape and Reel Packaging
- Hermetic Seal

APPLICATIONS:

- Impact Detection
- Arming / Fuzing
- Artillery, Launch
- More





AT-2150-B Pad Dimensions (micrometers) as viewed from pad side of device

Specifications

OPERATING CHARACTERISTICS:

Sensitivity	+Z (normal to PCB)	
Contact Acceleration Threshold Range		g
Contact Type (3)		J
Response Time (2)		μS
Reset		r
ELECTRICAL CHARACTERISTICS		
Contact Resistance (1)	< 10	ohms
Insulation Resistance (min.)	1000	Mohm
Breakdown Voltage	>200	VDC
ENVIRONMENTAL RATINGS:		
Operate Temperature Range	55 to +125	°C
Storage Temperature Range		°C
PCB/Pad Shear Force	> 20	N
PHYSICAL CHARACTERISTICS:		
Nominal Dimensions (LxWxH)	1.84 x 1.84 x 1.3	mm

(1) Contact resistance is dependent on input pulse acceleration level.

ROHS Compliant ?Yes

- (2) Response time depends upon input pulse profile
- (3) Electrical connection between pads B (bottom) and C (common) is normally open and is closed while acceleration is greater than the contact acceleration threshold.

Note that the information on this data sheet is for reference only.

Please verify the specifications as well as suitability for your application by consulting our engineering department.

This product and related technical data are controlled for export by the International Trade in Arms Regulations. Any sale, export, transfer or re-sale, in any form, requires the prior written approval of the U.S. Department of State.

 mm^3

milligrams